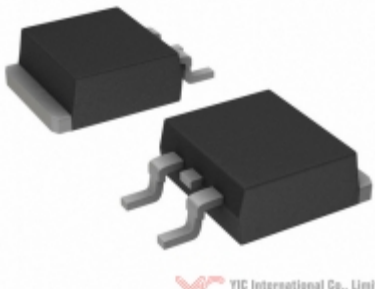

	<h2 style="color: red;">FQB3P20TM</h2>
 <p>Image may be representation. See specs for product details.</p>	Hersteller-Teilenummer: FQB3P20TM
	Hersteller / Marke: AMI Semiconductor / ON Semiconductor
	Teil der Beschreibung: MOSFET P-CH 200V 2.8A D2PAK
	Datenblätter:  FQB3P20TM.pdf
	RoHs Status: Bleifrei / RoHS-konform
	Lagerzustand: New original, 2245 pcs Stock Available.
Liefern von: Hong Kong	
Versandweg: DHL/Fedex/TNT/UPS/EMS	

Spezifikationen

Teilenummer	FQB3P20TM
Hersteller	AMI Semiconductor / ON Semiconductor
Beschreibung	MOSFET P-CH 200V 2.8A D2PAK
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	2245 pcs Stock
detaillierte Beschreibung	P-Channel 200V 2.8A (Tc) 3.13W (Ta), 52W (Tc)
Serie	QFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	TO-263-3, D ² Pak (2 Leads + Tab), TO-263AB
Supplier Device-Gehäuse	D ² PAK (TO-263AB)
Verlustleistung (max)	3.13W (Ta), 52W (Tc)
Typ FET	P-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	200V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	2.8A (Tc)
Rds On (Max) @ Id, Vgs	2.7 Ohm @ 1.4A, 10V
VGS (th) (Max) @ Id	5V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	8nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	250pF @ 25V
Antriebsspannung (Max Rds On, Min Rds On)	10V
Vgs (Max)	±30V
Verpackung	Tape & Reel (TR)
Bleifreier Status / RoHS-Status	Lead free / RoHS Compliant
Feuchtigkeitsempfindlichkeitsniveau (MSL)	1 (Unlimited)



















































FQB3P20TM ist neu im Original, Suche FQB3P20TM Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie FQB3P20TM AMI Semiconductor / ON Semiconductor mit Garantie und Vertrauen. Anfrage FQB3P20TM: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>FQB3N90TM AMI Semiconductor / ON Semiconductor MOSFET N-CH 900V 3.6A D2PAK</p>	 <p>FQB3N90 FCS FQB3N90 FCS</p>	 <p>FQB3P50TM Fairchild/ON Semiconductor MOSFET P-CH 500V 2.7A D2PAK</p>	 <p>FQB41N15D FAIRCHILD FAIRCHILD TO-263</p>
 <p>FQB3P20TM Fairchild/ON Semiconductor MOSFET P-CH 200V 2.8A D2PAK</p>	 <p>FQB3P50TM AMI Semiconductor / ON Semiconductor MOSFET P-CH 500V 2.7A D2PAK</p>	 <p>FQB44N10 Fairchi FQB44N10 Fairchi</p>	 <p>FQB3N80TM Fairchild/ON Semiconductor MOSFET N-CH 800V 3A D2PAK</p>

heiße Teile

Mehr

 FQB33N10LTM	 FQB33N10LTM	 FQB33N10TM	 D FQB33N10TM	 FQB34N20
 FQB34N20L	 FQB34N20LTM	 D FQB34N20LTM	 FQB34N20TM	 FQB34N20TM_AM002
 FQB34P10	 FQB34P10TM	 FQB34P10TM	 FQB34P10TM_F085	 FQB3N25TM
 D FQB3N25TM	 FQB3N30TM	 FQB3N30TM	 FQB3N40TM	 FQB3N40TM
 FQB3N60C	 FQB3N80TM	 FQB3N80TM	 FQB3N90TM	 FQB3N90TM
 FQB3P20TM	 FQB3P50TM	 D FQB3P50TM	 FQB44N10	 FQB44N10TM
 FQB44N10TM	 D FQB46N15	 FQB46N15TM	 FQB47P06	 FQB47P06TM
 FQB4N20L	 FQB4N20LTM	 FQB4N20LTM	 FQB4N20TM	 FQB4N20TM
 FQB4N25TM	 FQB4N25TM	 FQB4N20TM	 D FQB4N50TM	 FQB4N50TM
 FQB4N60C	 FQB4N80TM	 FQB4N80TM	 FQB4N90TM	 FQB4N90TM

Contact us: Info@Y-IC.com

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